NSN 5961-01-010-5797

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-010-5797 **Inclosure Material:** Glass **Overall Length:** Between 0.295 inches and 0.305 inches **Terminal Length:** 0.190 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.44 forward voltage, total rms **Current Rating Per Characteristic:** 300.00 milliamperes forward current, average megahertz **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 solder stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0